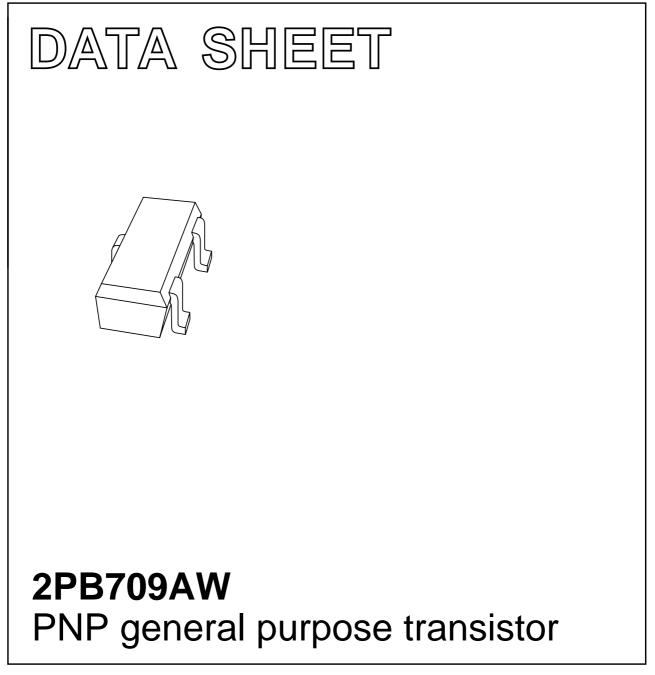
DISCRETE SEMICONDUCTORS



Product specification

2002 Jun 26



FEATURES

- High collector current (max. 100 mA)
- Low collector-emitter saturation voltage (max. 500 mV).

APPLICATIONS

• General purpose switching and amplification.

DESCRIPTION

PNP transistor in an SC-70 (SOT323) plastic package. NPN complement: 2PD601AW

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾
2PB709AQW	N5*
2PB709ARW	N7*
2PB709ASW	N9*

Note

- 1. * = p: made in Hong Kong.
 - * = t: made in Malaysia.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	-45	V
V _{CEO}	collector-emitter voltage	open base	_	-45	V
V _{EBO}	emitter-base voltage	open collector	_	-6	V
I _C	collector current (DC)		_	-100	mA
I _{CM}	peak collector current		-	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	-	200	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Note

1. For mounting conditions, see "Thermal considerations and footprint design for SOT323 in the General Part of Data Handbook SC18".

PINNING

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	

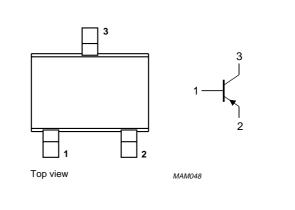


Fig.1 Simplified outline SC-70 (SOT323) and symbol.

2PB709AW

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	625	K/W

Note

1. For mounting conditions, see "Thermal considerations and footprint design for SOT323 in the General Part of Data Handbook SC18".

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$I_E = 0; V_{CB} = -45 V$	_	-10	nA
		$I_E = 0; V_{CB} = -45 \text{ V}; T_j = 150 \text{ °C}$	-	-5	μA
I _{EBO}	emitter-base cut-off current	$I_{C} = 0; V_{EB} = -5 V$	_	-10	nA
h _{FE}	DC current gain	$I_{C} = -2 \text{ mA}; V_{CE} = -10 \text{ V}$			
	2PB709AQW		160	260	
	2PB709ARW		210	340	
	2PB709ASW		290	460	
V _{CEsat}	collector-emitter saturation voltage	$I_{C} = -100 \text{ mA}; I_{B} = -10 \text{ mA};$ note 1	-	-500	mV
C _c	collector capacitance	$I_E = i_e = 0; V_{CB} = -10 V;$ f = 1 MHz	-	5	pF
f _T	transition frequency	$I_{C} = -1 \text{ mA}; V_{CE} = -10 \text{ V};$			
	2PB709AQW	f = 100 MHz	60	_	MHz
	2PB709ARW		70	_	MHz
	2PB709ASW		80	_	MHz

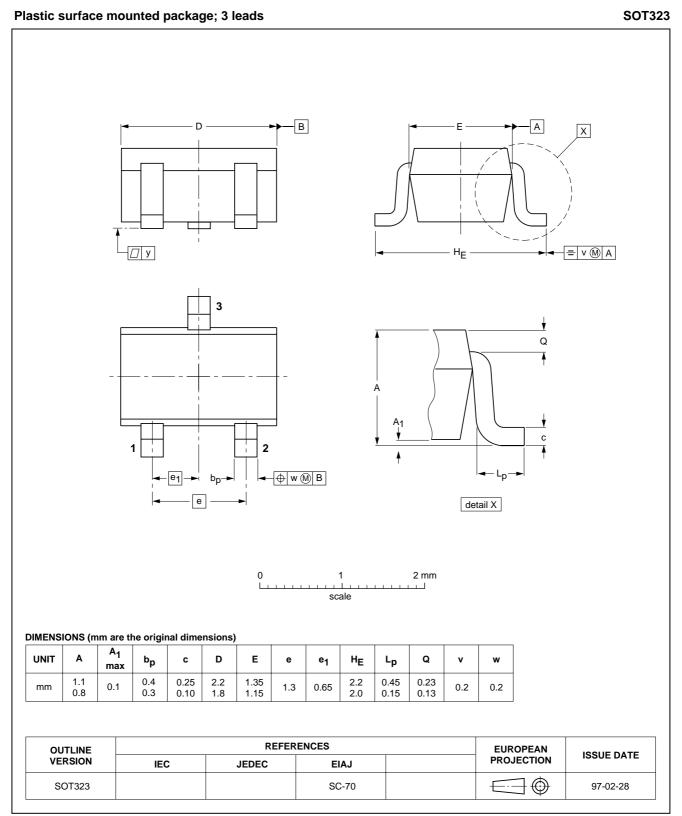
Note

1. Pulse test: $t_p \leq 300 \ \mu s; \ \delta \leq 0.02.$

2PB709AW

PNP general purpose transistor

PACKAGE OUTLINE



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DATA SHEET STATUS

DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

Notes

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- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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NOTES

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NOTES

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